

| Ref # | Hits | Search Query | DBs | Default Operator | Plurals | Time Stamp |
|-------|------|--|---|------------------|---------|------------------|
| L1 | 6 | (voltage same flatten\$3) same (clip\$3 near circuit) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2005/10/23 10:28 |
| L2 | 3 | (voltage same flatten\$3) same ((substrate or wafer) near (bias near power)) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2005/10/23 10:14 |
| L3 | 8 | watanabe-seiichi.in. and (voltage same flatten\$3) | US-PGPUB; USPAT | OR | OFF | 2005/10/23 10:22 |
| L4 | 5 | tamura-hitoshi.in. and (voltage same flatten\$3) | US-PGPUB; USPAT | OR | OFF | 2005/10/23 10:23 |
| L5 | 8 | yasui-naoki.in. and (voltage same flatten\$3) | US-PGPUB; USPAT | OR | OFF | 2005/10/23 10:23 |
| L6 | 12 | (bias\$3 near power) same (clip\$3 near circuit) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2005/10/23 10:28 |